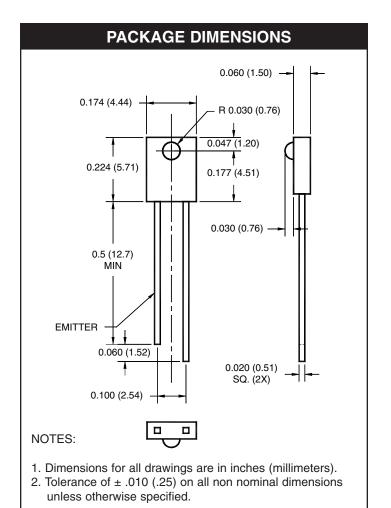
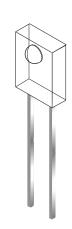
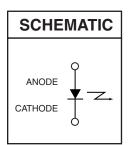
PLASTIC INFRARED LIGHT EMITTING DIODE

QEE213







DESCRIPTION

The QEE213 is a 940nm GaAs LED encapsulated in a medium angle, thin plastic sidelooker package.

FEATURES

Wavelength = 940 nm, GaAs

• Package Type: Sidelooker

Medium Beam Angle, 50°

• Clear Plastic Package

• Matched Photosensors: QSE213 and QSE243



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ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)							
Parameter	Symbol	Rating	Unit				
Operating Temperature	T _{OPR}	-40 to + 100	°C				
Storage Temperature	T _{STG}	-40 to + 100	°C				
Soldering Temperature (Iron)(2,3,4)	T _{SOL-I}	240 for 5 sec	°C				
Soldering Temperature (Flow)(2,3)	T _{SOL-F}	260 for 10 sec	°C				
Continuous Forward Current	I _F	100	mA				
Reverse Voltage	V _R	5	V				
Peak Forward Current ⁽⁵⁾	I _{FP}	1	A				
Power Dissipation ⁽¹⁾	P _D	100	mW				

ELECTRICAL / OPTICAL CHARACTERISTICS (TA =25°C)								
Parameter	Test Conditions	Symbol	Min	Тур	Max	Units		
Peak Emission Wavelength	I _F = 100 mA	l _P	_	940		nm		
Emission Angle	I _F = 100 mA	U	_	±25	_	Deg.		
Forward Voltage	$I_F = 100 \text{ mA}, \text{ tp} = 20 \text{ ms}$	V _F	_		1.5	V		
Reverse Current	$V_R = 5 V$	I _R	_	_	10	μΑ		
Radiant Intensity	$I_F = 100 \text{ mA}, \text{ tp} = 20 \text{ ms}$	le	2	_	_	mW/sr		
Rise Time	I _F = 100 mA	t _r	_	1	_	μs		
Fall Time	tp = 100 μs, T = 10 mS	t _f	_	1	_	μδ		

NOTES

- 1. Derate power dissipation linearly 2.67 mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6 mm) minimum from housing.
- 5. Pulse conditions: $tp = 100 \mu s$, T = 10 ms.



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TYPICAL PERFORMANCE CURVES

Fig. 1 Forward Current vs. Forward Voltage I_F Pulsed IF - FORWARD CURRENT (mA) $t_{pw} = 100 \mu s$ $T_A = 25^{\circ}C$ 10² 10¹ 100 3 5 V_F - FORWARD VOLTAGE (V)

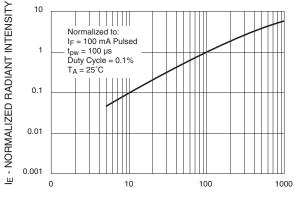
Fig. 2 Forward Voltage vs. Ambient Temperature VF - FORWARD VOLTAGE (V) I_F Pulsed t_{pw} = 100 μs Duty Cycle = 0.1% 0.0 -40 20 100

TA - AMBIENT TEMPERATURE (°C)

Fig. 4 Radiation Diagram

vs. Forward Current 10 Normalized to: I_F = 100 mA Pulsed

Fig. 3 Normalized Radiant Intensity



100 110 120 130 140 150 160 170 10 180 1.0 0

IF - FORWARD CURRENT (mA)



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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.